SURFACE PREPARATION

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Required Procedures for Qualifying SRF Cavities

- Degreasing surfaces to remove contaminates
- Chemical removal of exterior films incurred from welding
- Removal of damage layer of niobium from fabrication (~150 μm)
- Removal of hydrogen from bulk Nb
- Mechanical tuning
- Chemical removal of internal surface for clean assembly (10-20 μm)
 - Additional "cleaning" steps if Electropolishing (EP) is used
- High Pressure Rinsing (HPR) to remove particulates from interior surfaces (incurred during chemistry and handling)
- Drying of cavity for assembly in cleanroom (reduce risk of particulate adhesion and reduce wear on vacuum systems)
- Clean assembly
- Clean evacuation
 If cavity meets specs after cryo-RF test.
- Low-temperature baking









Additional Steps for Cavity String

- Final mechanical tuning
- He-vessel welding
- Degreasing
- Final material removal (10-20 μm)
- Final HPR
- Horizontal assembly into cavity-string
- Evacuation of cavity string









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Degreasing with Ultrasonic Agitation

Why is degreasing needed

- To remove grease, oil and finger prints from cavity surfaces
- To remove surface contamination due to handling, RF measurements and QA inspection





- Ultrasonic degreasing with detergent (Micro-90[®], Liqui-Nox[®]), 1%-2% concentration, and ultra pure water
- Usually performed in Hepa filtered air
- Water quality is good, 18 MΩ cm, Filtration > 0.2μm
- Manually or semi-automated processes available
- Problem: Parts are wet and vulnerable to particulate contamination









Ultrasonic Cleaning

- Immersion of components in DI water and detergent medium
- Wave energy forms microscopic bubbles on component surfaces.
 Bubbles collapse (cavitation) on surface loosening particulate matter.
- Transducer provides high intensity ultrasonic fields that set up standing waves. Higher frequencies lowers the distance between nodes which produce less dead zones with no cavitation.
- Ultrasonic transducers are available in many different wave frequencies from 18 kHz to 120 kHz, the higher the frequency the lower the wave intensity.

Cavities and all hardware components (Flanges, nuts & bolts...) have to be degreased with ultrasonic cleaning

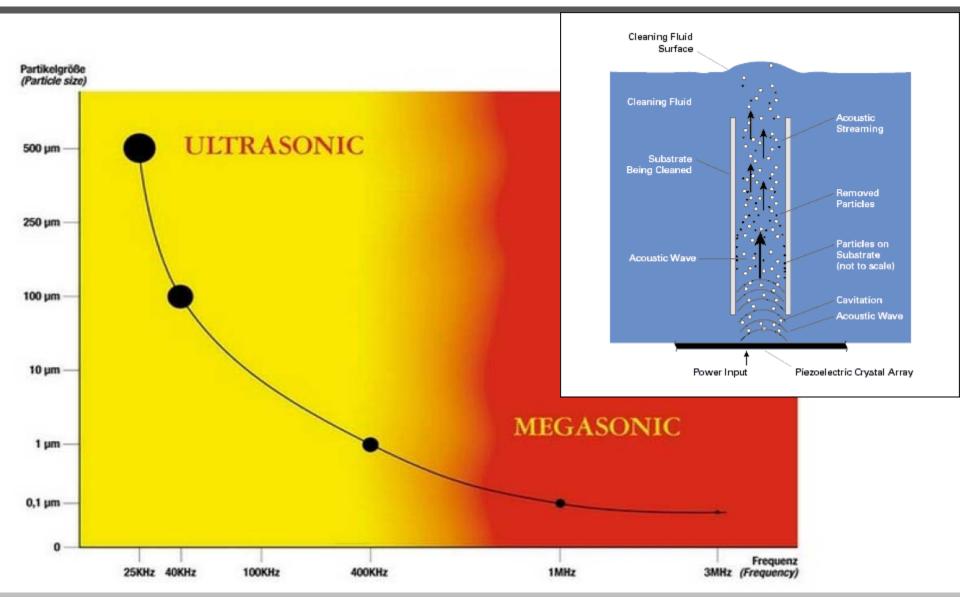








Megasonic Cleaning



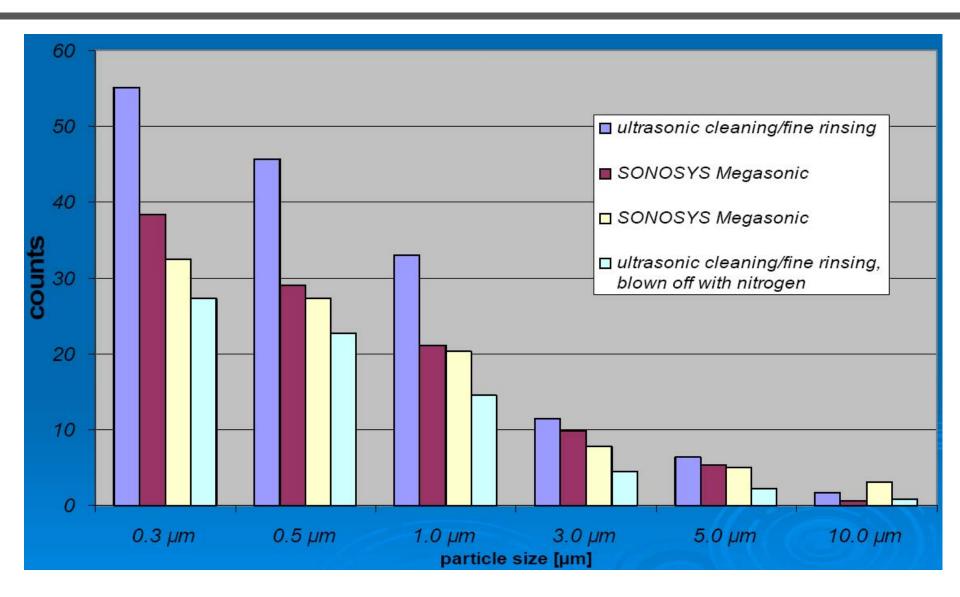








Studies on Efficient Cleaning Methods











Example on Nb Sample

Test on cleaning procedure/detergent: Nb sample polluted with grease and oil













Ultrasonic Tanks for Cavity Cleaning









Required Procedures for Qualifying SRF Cavities

- Degreasing surfaces to remove contaminates
- Chemical removal of exterior films incurred from welding
- Removal of damage layer of niobium from fabrication (~150 μm)
- Removed of bydrogen from bulk Nb Chemical:
- Me
 Buffered Chemical
- Polishing (BCP)
 Electropolishing (EP)

Mechanical
Centrifugal Barrel Polishing
(CBP)

- Additional "cleaning" steps if Electropolishing (EP) is used
- High Pressure Rinsing (HPR) to remove particulates from interior surfaces (incurred during chemistry and handling)
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- Clean assembly
- Clean evacuation









Acid Etching of Sub-components & Cavities:



Implementation: (BCP or EP)

- Sub-components require
 - Removal of oxides which come from fabrication steps → lower losses and improve sealing
- Cavities require:
 - Interior chemistry to remove damaged surface layer incurred in welding and deep drawing (100-200µm)
 - Exterior chemistry to remove surface oxides that occurred in welding (10-30μm)
- Subcomponents usually processed by hand in wet bench
- Acid quality usually electronic grade or better, low in contaminants
- Acid temperature control required to prevent additional absorption of hydrogen (Q-disease)
- Acid mixture difficult to QA

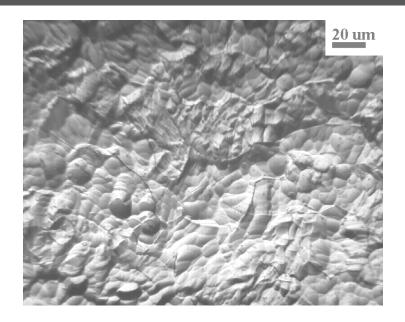


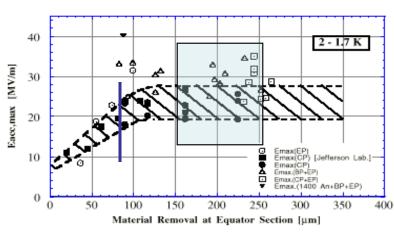


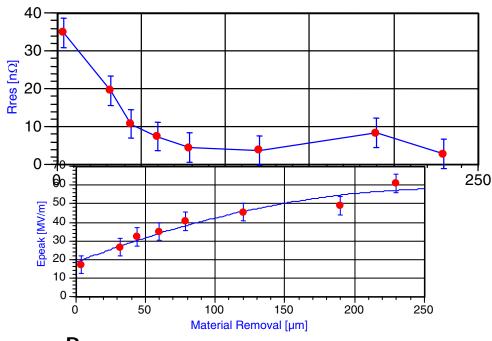




The Need For Material Removal







P. Kneisel

K. Saito

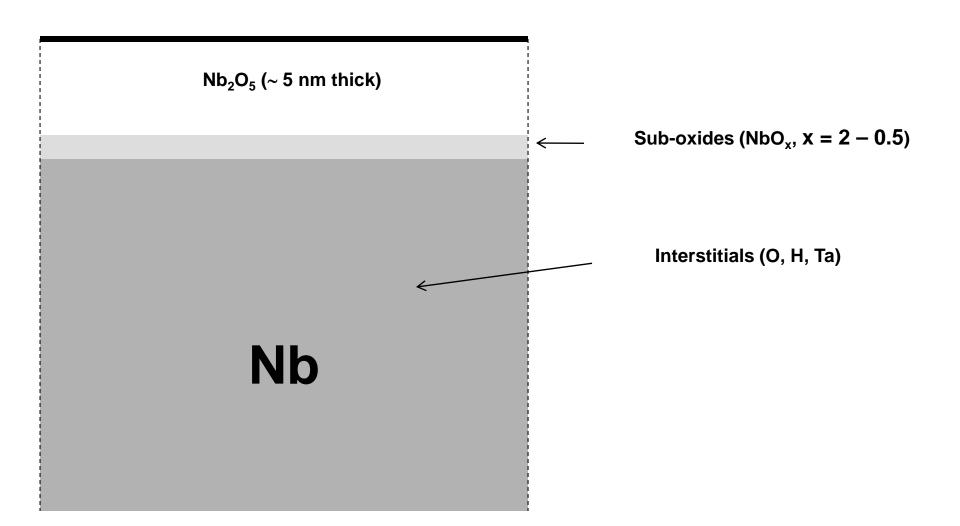








Nb Surface











Buffered Chemical Polish (BCP)

HF (49%), HNO₃ (65%), H₃PO₄ (85%) Mixture 1:1:1, or 1:1:2 by volume typical

Oxidation

 $2Nb + 5HNO_3 \rightarrow Nb_2O_5 + 5NO_2$

Brown gas

Reduction

$$Nb_2O_5 + 6HF \rightarrow H_2NbOF_5 + NbO_2F 0.5H_2O + 1.5H_2O$$

 $NbO_2F 0.5H_2O + 4HF \rightarrow H_2NbOF_5 + 1.5H_2O$

Reaction exothermic! Use H₃PO₄ as "buffer" to slow reaction rate





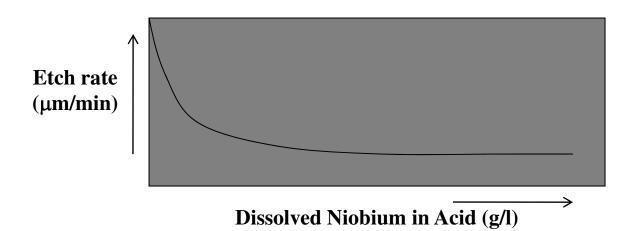




Use of BCP:

- 1:1:1 still used for etching of subcomponents (etch rates of $\sim 8 \ \mu m/min)$
- 1:1:2 used for most cavity treatments (etch rates of \sim 3 μ m/min)
 - Agitation necessary → reaction products at surface
 - Acid is usually cooled to 10-15 $^{\circ}$ C (1-3 μ m/min) to control the reaction rate and Nb surface temperatures (reduce hydrogen absorption)

Acid wasted after 15 g/l Nb



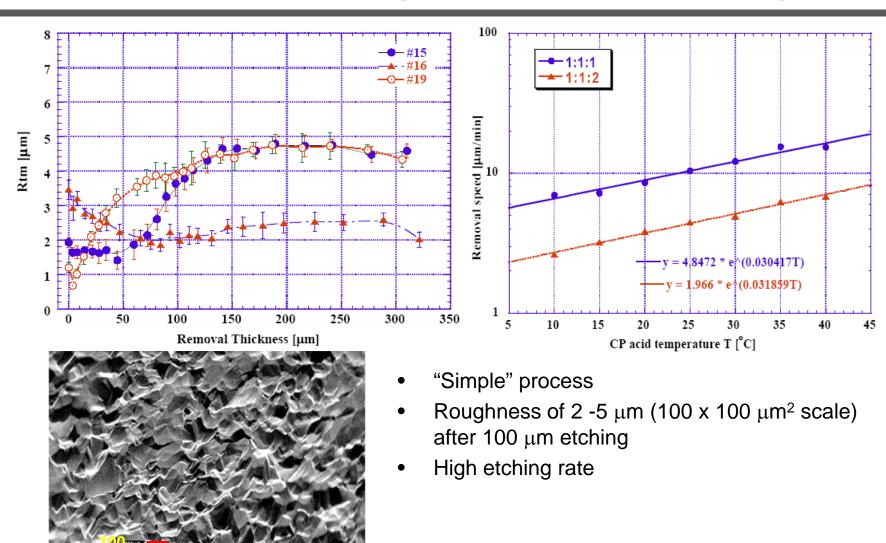








BCP: Surface Roughness and Etching Rate











BCP Systems for Cavity Etching

- Bulk & Final chemistry
 - Bulk removal of (100-200 μm)
 - Final removal of (5-20 µm)
 to remove any additional
 damage from QA steps and
 produce a fresh surface



- Cavity held vertically
- Closed loop flow through style process, some gravity fed system designs
- Etch rate 2x on iris then equator, if no stirring mechanism
- Temperature gradient causes increased etching from one end to the other
- · Manually connected to the cavity but process usually automated



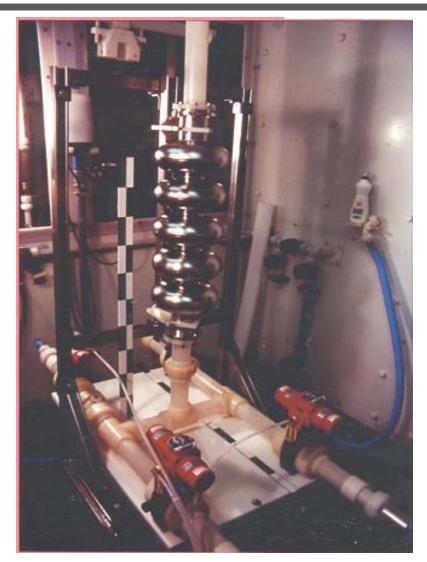




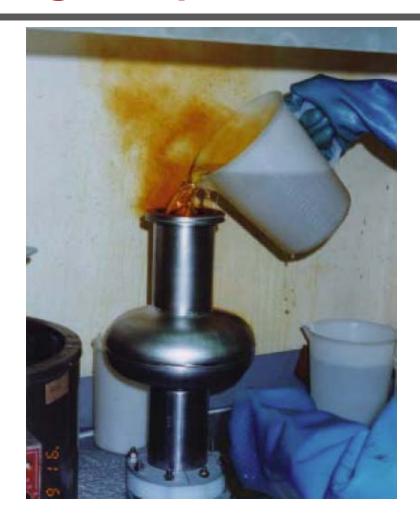




Chemical Etching Setups



Old system for CEBAF cavities



BCP of single cell cavity under chemical flow hood









Chemical Etching of Outer Surface

- ~ 20 um are removed from the outer surface of the cavity by BCP to remove "dirty" layer after fabrication in order to improve the heat transfer at the Nb/LHe interface (Kapitza resistance)
- Some labs do this as part of cavity preparation procedure (DESY), some don't (JLab)
- No clear influence on cavity performance

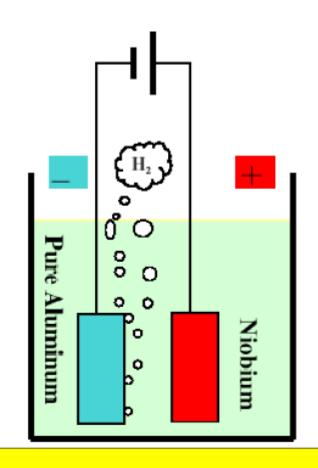








Electropolishing



Acid:

 H_2SO_4 (>93%): HF(46%)=10:1 V/V

9:1

Electropolishing (EP) of Niobium:

- Both electrodes are immersed in electrolyte
- A voltage is applied between Nb (anode) and counter electrode (cathode, Al)

Basic reactions:

Oxidation

$$2\text{Nb} + 5\text{SO}_4^{2-} + 5\text{H}_2\text{O} \rightarrow \text{Nb}_2\text{O}_5 + 10\text{H}^+ + 5\text{SO}_4^{2-} + 10\text{e}^-$$

Reduction

$$Nb_2O_5 + 6HF \rightarrow H_2NbOF_5 + NbO_2F 0.5H_2O + 1.5H_2O$$

NbO₂F 0.5H₂O + 4HF → H₂NbOF₅ + 1.5H₂O **Hydrogen gas produced at cathode**

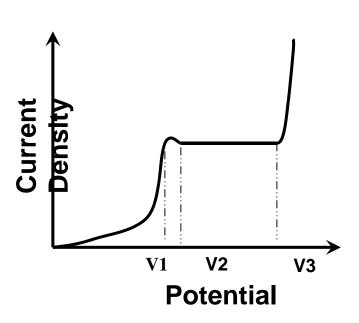








I-V Curve



- 0-V2: Concentration Polarization occurs, active dilution of niobium
- V2-V3: Limiting Current Density, viscous layer on niobium surface
- >V3: Additional Cathodic
 Processes Occur, oxygen gas
 generated

Power Supply Electrometer Ref Electrod Nb 1 : Anode polarization curve, Nb 2 : Cathode polarizatation curve, Al * 35 * The cathode current density duplicated Current density (mA/cm²) 01 12 05 50 00 in the curve 2 was divided by 10 - 2 "Platea 18 16 Voltage (V) (vs. MSE)

Electrode potentials should be measured wrt a Reference Electrode!





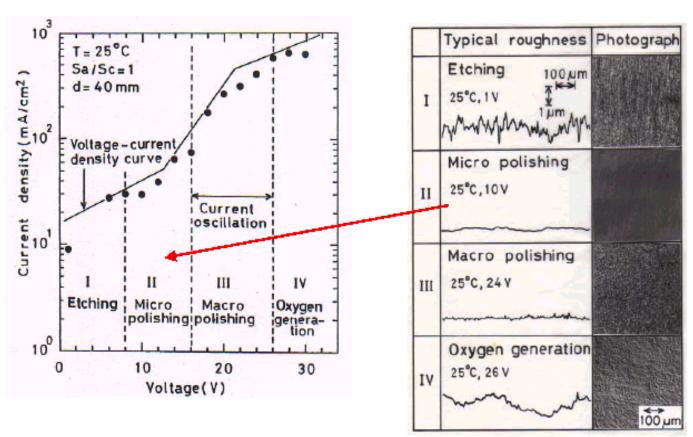




Good surface finish when in right I(V)

Talk by K.Saito in JLAB on Oct. 2003

Micro and macro electropolishing in niobium EP



Kenji Saito, KEK, 1989



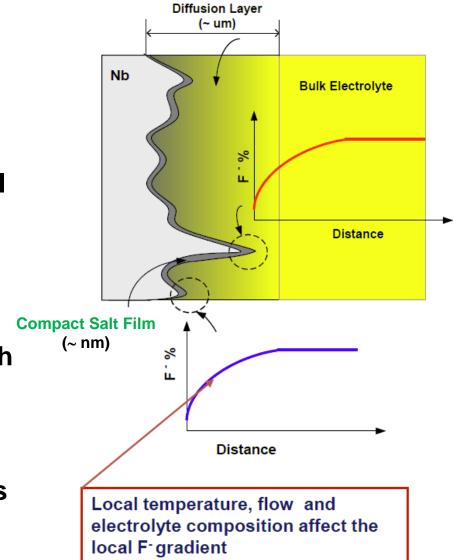






Basic Mechanism for EP

- Anodization of Nb in H₂SO₄ forces growth of Nb₂O₅
- F⁻ dissolves Nb₂O₅
- These competing processes result in current flow and material removal
- Above a certain anodization potential, the reaction rate plateaus, limited by how fast fresh F- can arrive at the surface (diffusion-limited)
- The diffusion coefficient sets a scale for optimum leveling effects











EP: tricky process

- The current density (30-100 mA/cm²) in the plateau region:
 - decreases linearly with lower HF/H₂SO₄ ratio
 - increases with increasing temperature
- Temperature during the process is maintained between 25 – 35 °C
- Current oscillations often observed during polishing (dynamic balance between oxide formation and dissolution). It's not a necessary condition for good surface finishing but indication of good processing parameters (temperature, voltage, agitation, HF concentration)

Finding the right balance among the processing parameters becomes complicated when polishing multi-cell cavities!

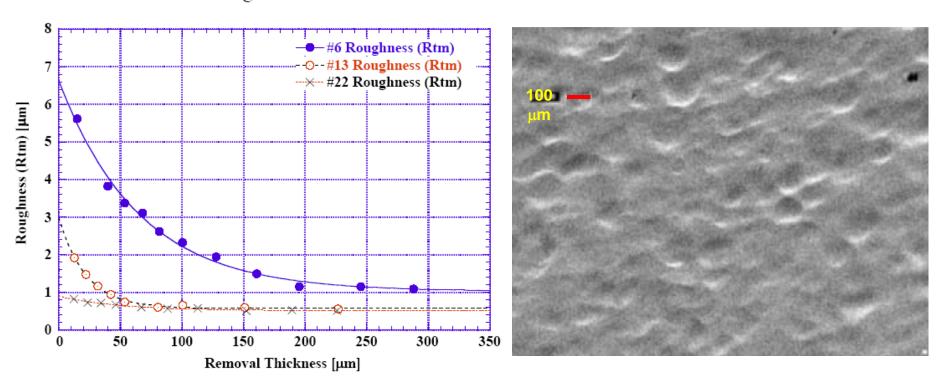






EP: Smooth Surface

Surface roughness with EP



Typical roughness of ~ 1 μ m (100 x 100 μ m² scale)

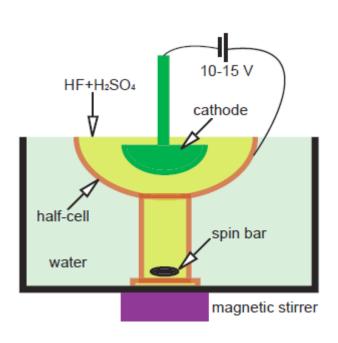








EP Setups: Half-Cells



R.L. Geng, Cornell Univ.



Material removal prior to final equatorial EBW

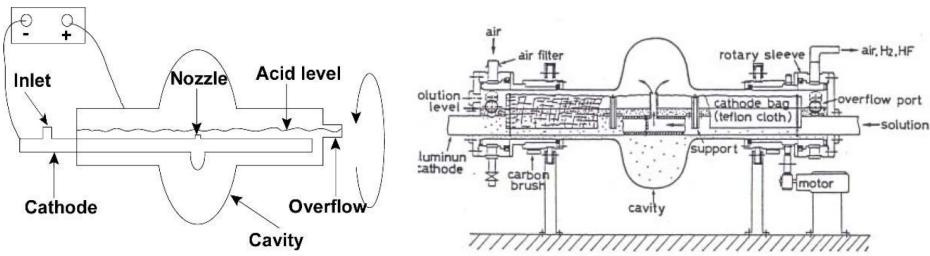


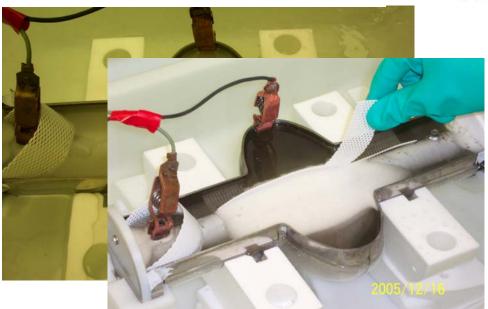






EP Systems: Single-Cell







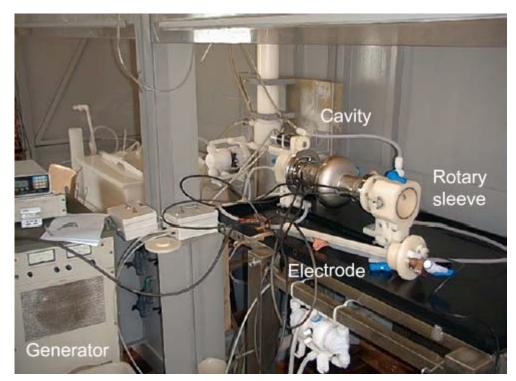


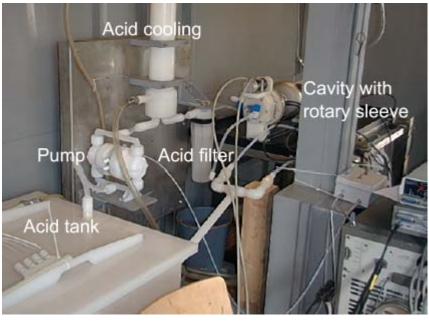






EP Systems: Single-Cell





Single-Cell setup at CERN Horizontal continuous electropolishing, polishing rate \sim 0.3 μ m/min









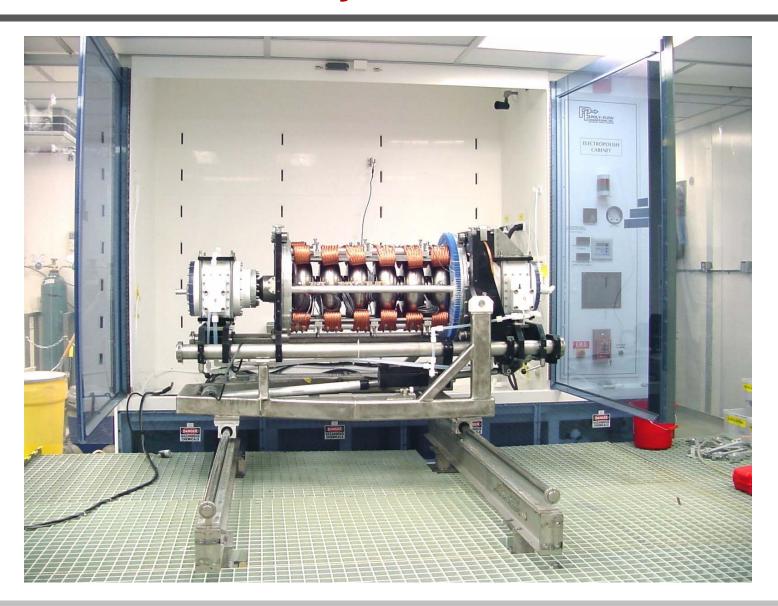


DESY









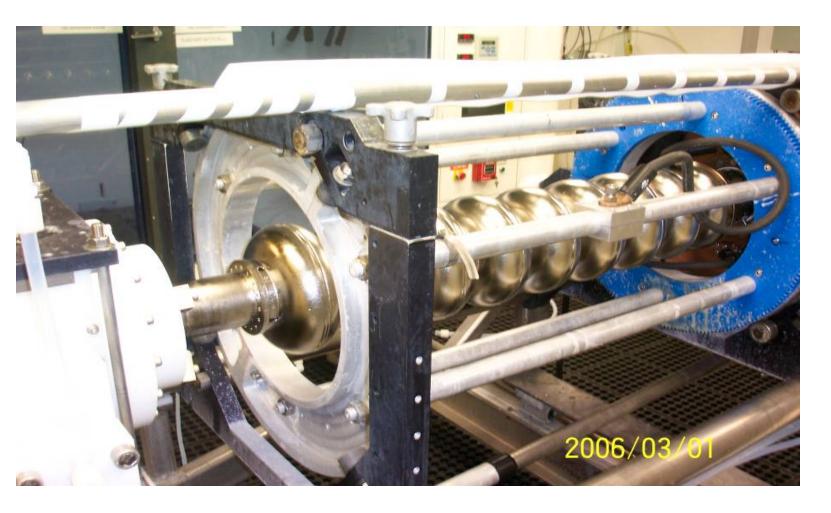
JLAB









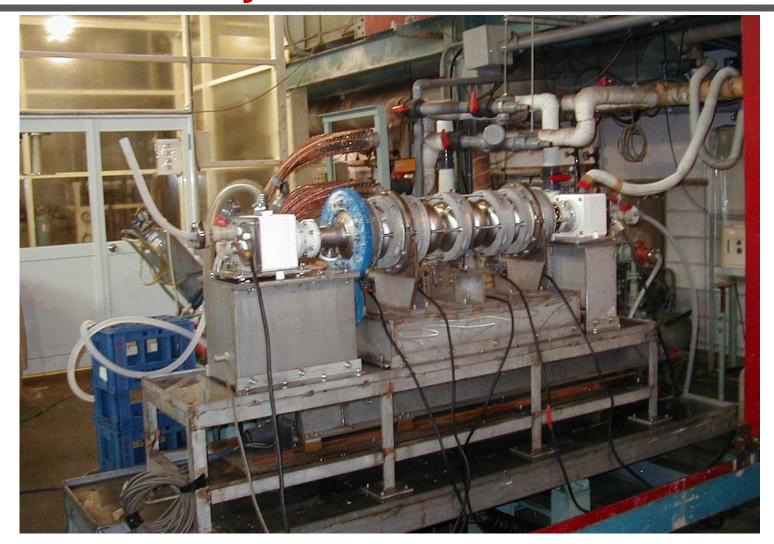


JLAB









Nomura Plating and KEK







EP Issues

- HF disappears quickly from electrolyte due to surface temperature and evaporation and must be added routinely
- Difficult to add HF to the Sulfuric, reaction looses HF plus adds water to electrolyte which causes matt finishes
- Sulfur precipitates found on niobium surfaces (insoluble) and in system piping (monoclinic), impossible to add meaningful filtration
- Removal of sulfuric from surfaces difficult and requires significant amounts of DI water, hydrogen peroxide or alcohol rinses
- Typically cavity processed horizontally, slowly rotated
- Etch rate 2x on iris then equator

Why bother with EP?

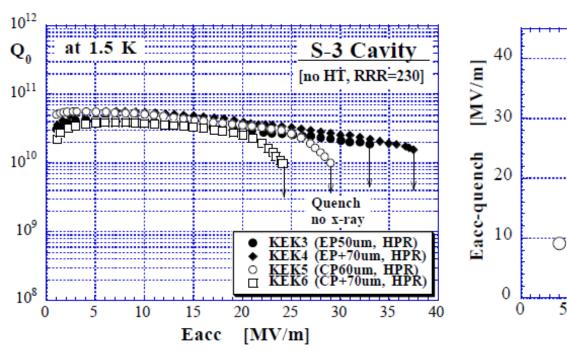


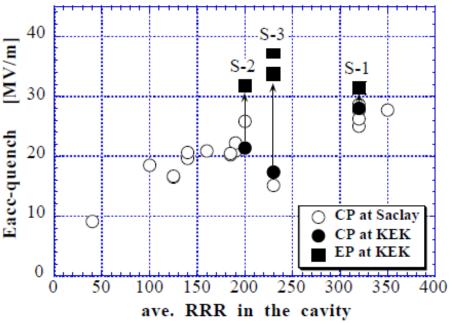






EP: achieving high accelerating field





1999, KEK

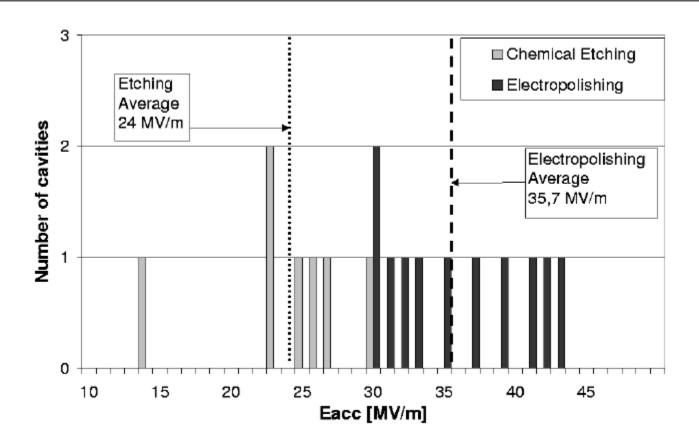








EP: achieving high accelerating field



2001, CERN-CEA-DESY Collaboration

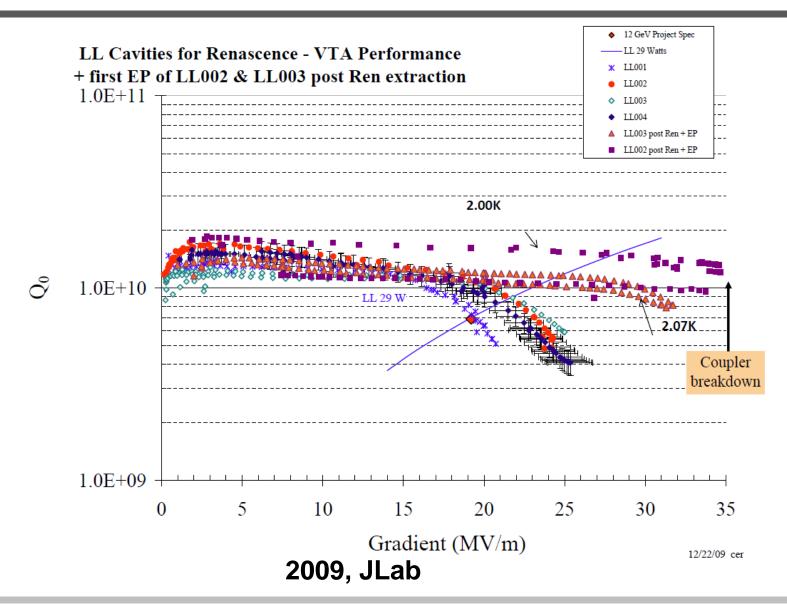








EP: achieving high accelerating field

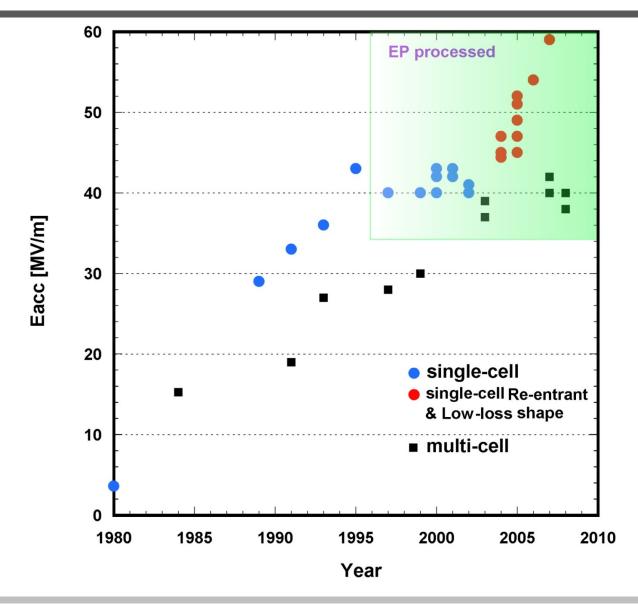








EP: achieving high accelerating field





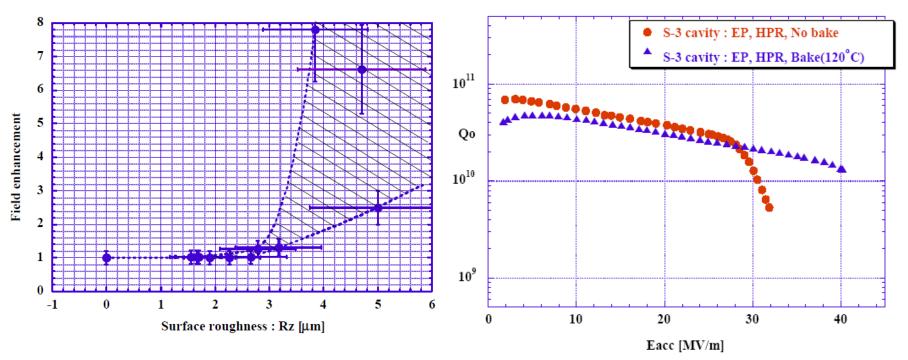






Why Is EP Better?

- Q-drop recovers after baking
- Smoother surface



$$E_{acc, ext{max}} \propto \frac{r \ H_{c, RF}}{\beta}$$

 β = magnetic field enhancement factor r = reduction of critical magnetic field due to "polluted" surface layer









EP: used also in low- β cavities for heavy ion accelerator





SRF cavities for ATLAS and future FRIB

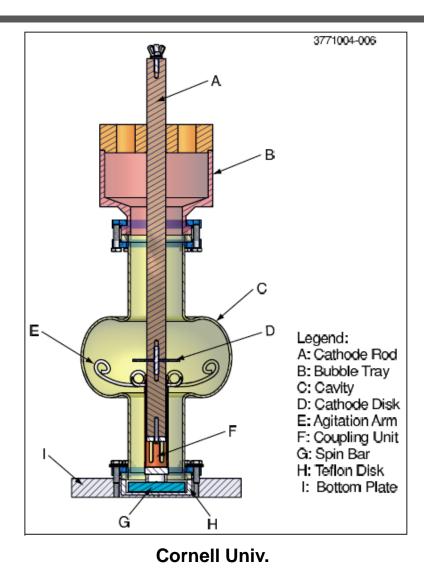
Argonne Nat'l Lab



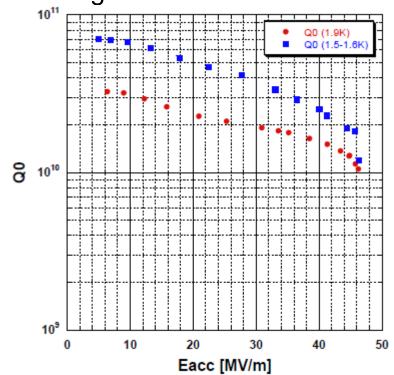




Vertical EP



- No rotary acid seals
- Twice removal rate than horizontally rotating EP
- No sliding electrical contacts
- No large acid reservoir and heat exchanger





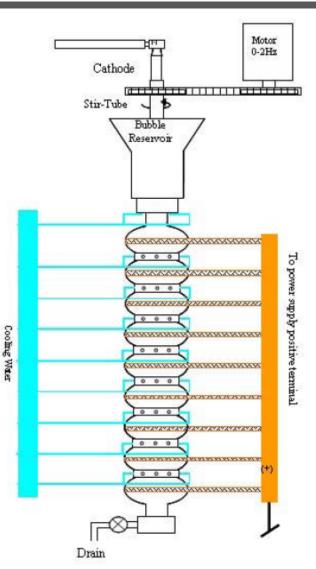


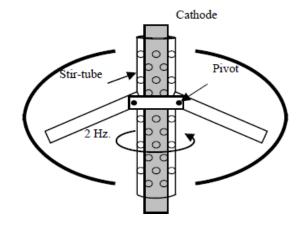


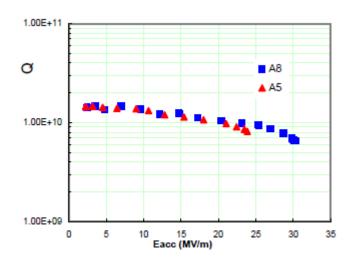


Vertical EP









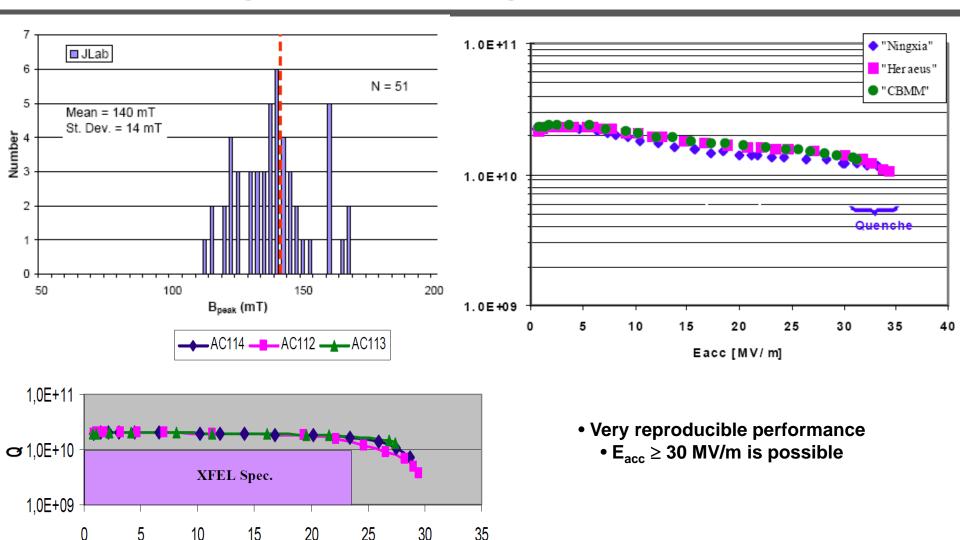








Challenge to EP: Large Grain Nb & BCP







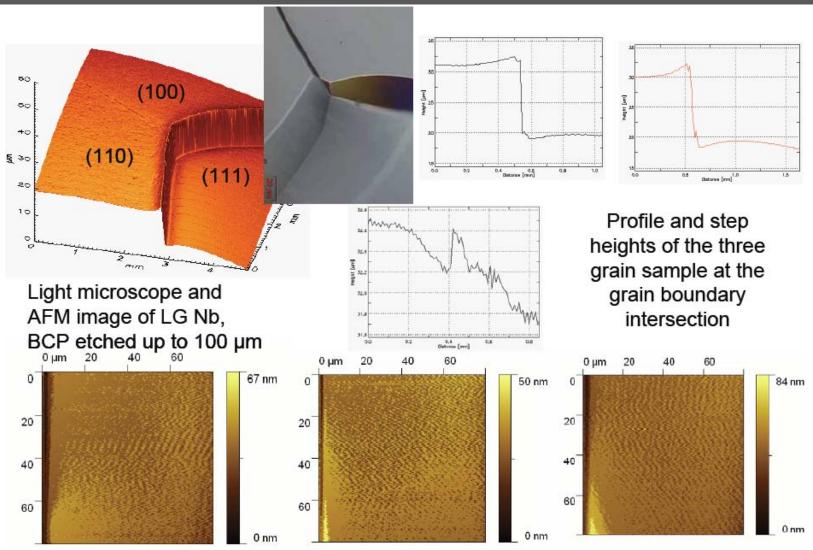


Eacc, MV/m





Large-Grain Nb Surface After BCP





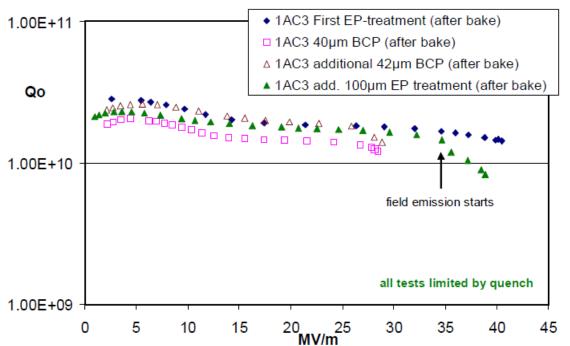








Challenge to EP: Large Grain Nb & BCP



	Quench gradient	Quench gradient
	after final EP	after final BCP
Large grain Nb	(33 – 43) MV/m	(25 – 30) MV/m
Fine grain Nb	$(36 \pm 4) \text{ MV/m}$	Data not sufficient

- Studies at DESY show higher Eacc after EP even for large-grain Nb
- The typical performance of large-grain Nb cavities treated by BCP would satisfy the requirements for most accelerator projects

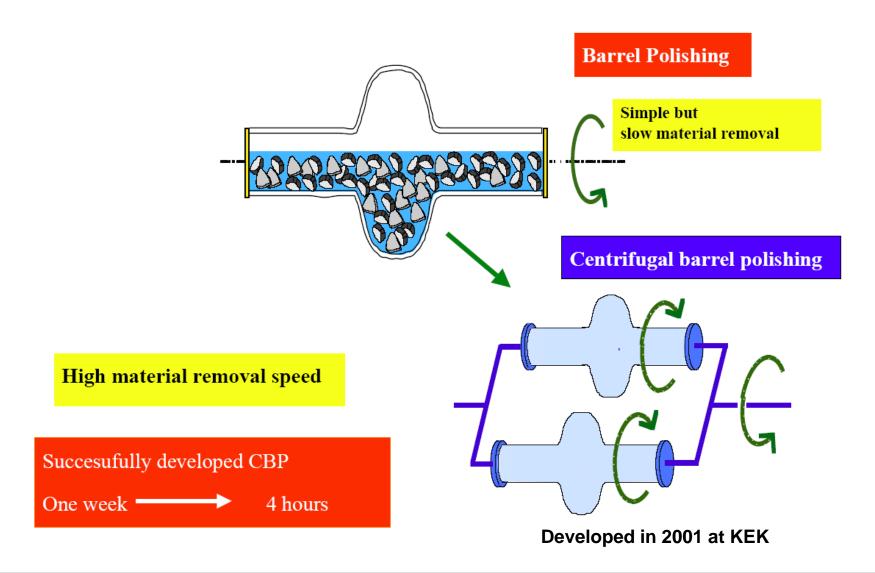








Centrifugal Barrel Polishing





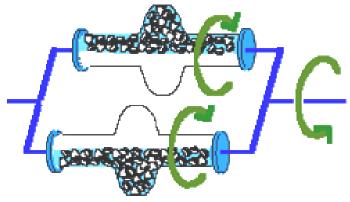






CBP Implementation

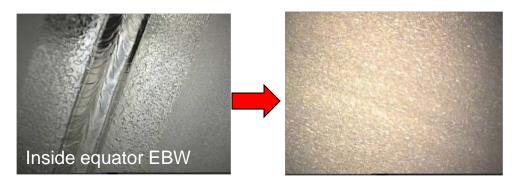
Centrifugal Barrel Polishing (CBP)





Implementation:

- Plastic stones and liquid abrasive added inside cavity and rotated
- Stones rubbing on surface removes material thus smoothing the surfaces (including weld areas)
- Benefit is less overall chemistry needed (80 μm) and smooth weld areas



• Removal of material 2x on equators then irises. Average removal rate $\sim 5~\mu\text{m/h}$









Barrel Polishing Machine at JLab







Removal rate ~ 3 – 4 μm/h











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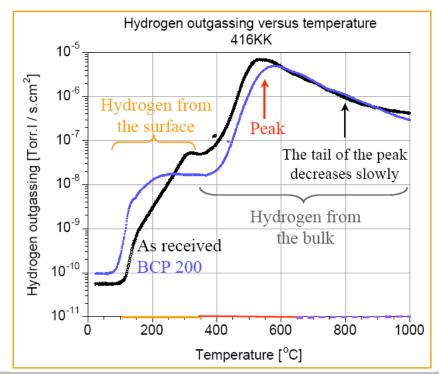






Heat Treatment for H-degassing

- H absorption occurs during chemical and/or mechanical material removal
- Reduce bulk H concentration in Nb to avoid Q-disease
- The heat treatment also "stress-relieves" the Nb
- Different parameters at different labs:
 - 600 °C/10 h at JLab
 - 800 °C/2 h at DESY
 - 750 °C/3 h at KEK







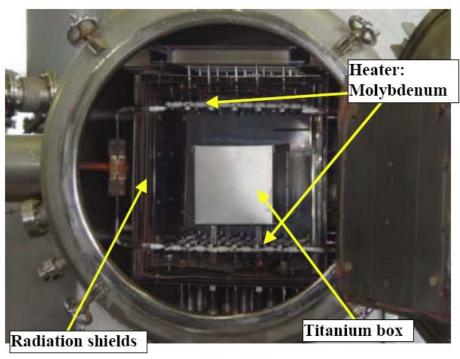




High Temperature Vacuum Furnace



Heat Treatment Furnace at JLab up to 1250 °C, P ≤ 10⁻⁶ Torr



Vacuum furnace in KEK : Temp.= 1300 °C max, Vac. = 1xE-6 torr

Use Residual Gas Analyzer to monitor the partial pressure of residual gases during heat treatment









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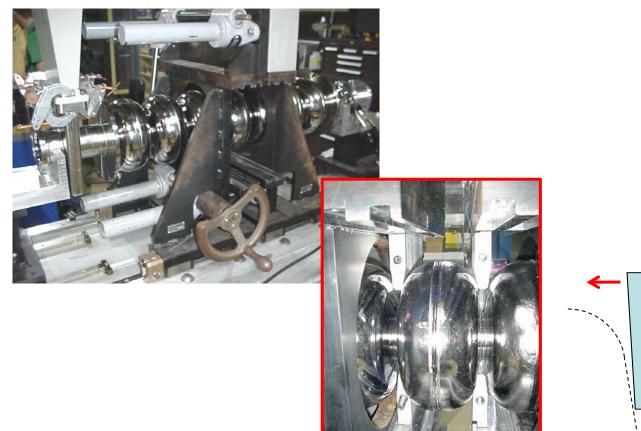


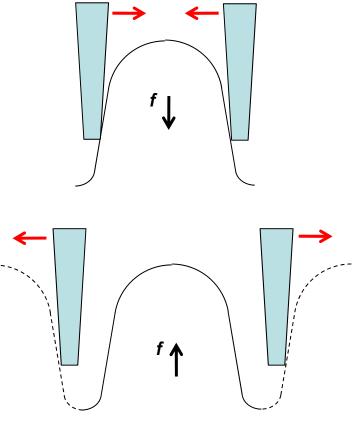




Mechanical Tuning

 Small mechanical adjustments to the cavity's cells to obtain flat field profile and desired frequency













Post-EP Cleaning

- Degreasing surfaces to remove contaminates
- Chemical removal of exterior films incurred from welding
- Removal of damage layer of niobium from fabrication (\sim 150 μ m)
- Removal of hydrogen from bulk Nb
- Mechanical tuning
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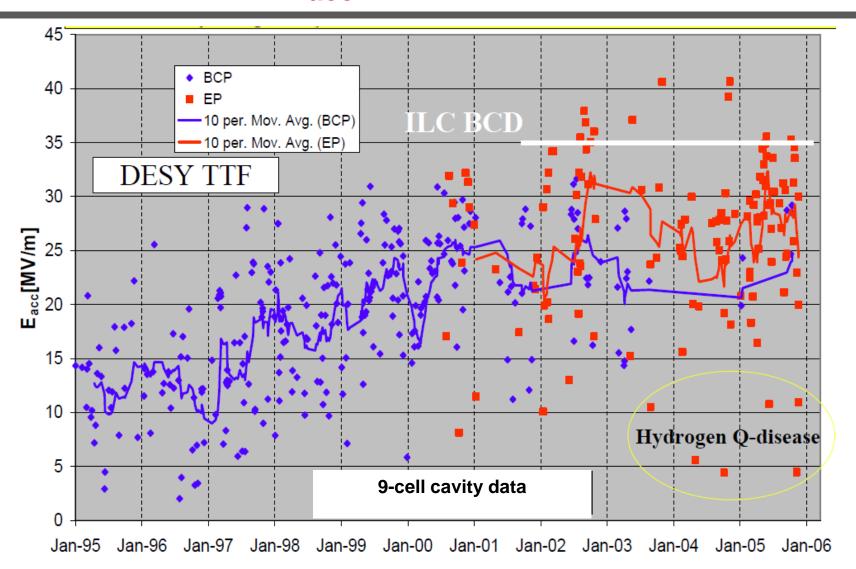








EP: high E_{acc} but large scattering





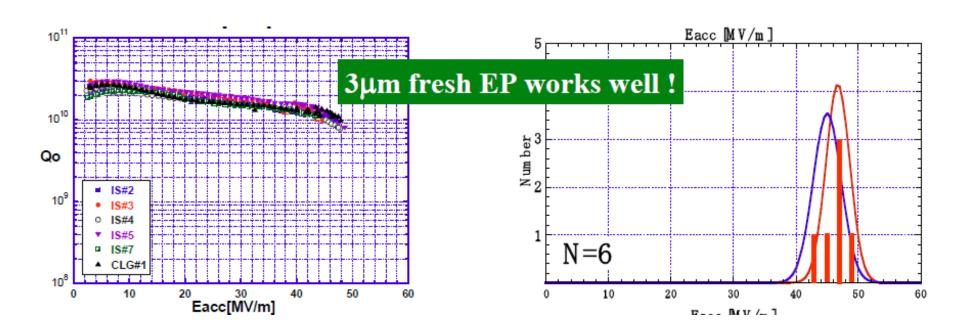






Post-EP Cleaning Processes

- Ethanol Rinse (DESY)
- "Flash" BCP (10 μm) (DESY)
- "Flash" EP (3 μm, fresh acid, no re-circulation) (KEK)
- Ultrasonic Degreasing with Micro-90 and hot water (JLab)











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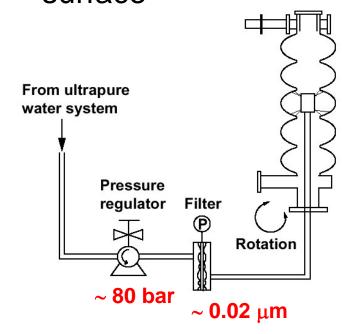






High Pressure Rinsing (HPR)

 SRF cavities cleaning method to remove particulates from handling and contaminants after chemistry from the inner surface





ACCEL Instruments









High Pressure Rinsing (HPR)

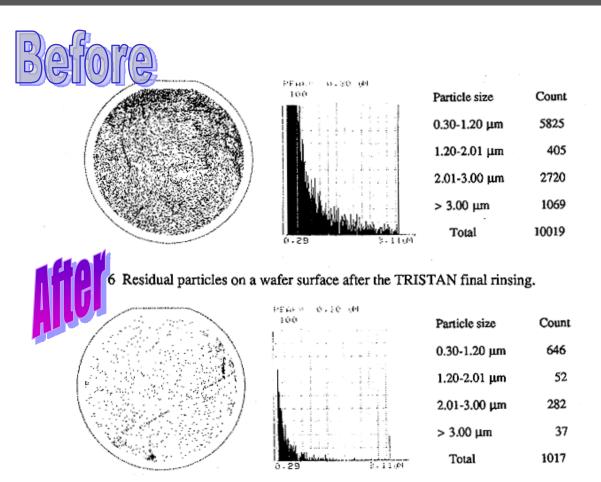




Fig. 7 Residual particle on a wafer surface after HPR.

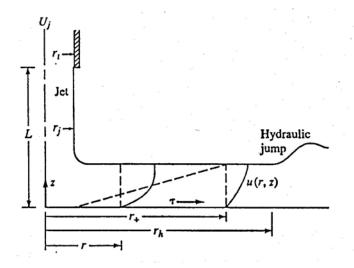


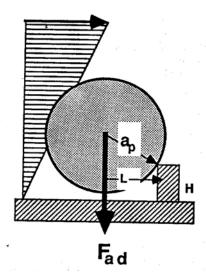






Particle Removal Mechanism





- Hydrodynamic model allows estimating the shear stress τ of the water jet, which depends on flow rate and pressure
- Particle removal by rolling if the water shear stress is greater than a critical shear stress τ₀, related to the particle size, adhesion force and surface roughness _____

$$\tau_0 = \frac{F_{ad}}{44a_p^2} \sqrt{2\frac{H}{a_p} + \left(\frac{H}{a_p}\right)^2}$$



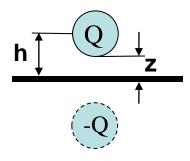






Adhesion Forces

Particle of diameter d



Adhesion forces:

Coulomb

• Capillary
$$F = \alpha \frac{Q^2}{4\pi\varepsilon_0 d^2}$$

$$F = 2\pi\gamma d$$

• Van der Waals $F=2\pi\gamma\,d$ γ : surface tension

• Electrical double layer

$$F = \frac{7.2 \text{eV}}{16\pi} \frac{d}{z^2}$$

$$F \propto \frac{\Delta \Phi^2 d}{z}$$

Example: 1 µm glass particle on

water 1.4×10⁻⁷ N

4.5×10⁻⁷ N

3×10⁻⁸ N

1×10⁻⁸ N





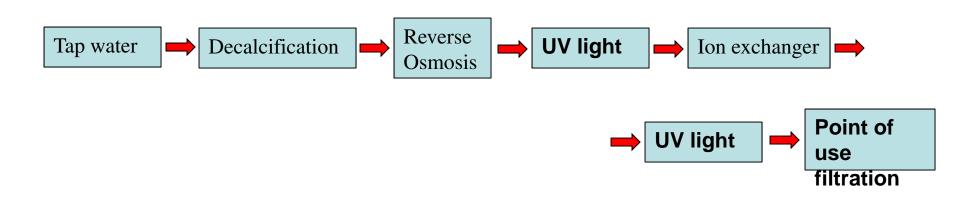




Ultrapure Water Quality

- Water quality of ultrapure water for SRF cavities preparation:
 - Resistivity: 18.2 MΩcm
 - Total oxydable carbon (TOC): < 5 ppb
 - Particulate counts (> 0.3 μm/l): < 10
 - Bacteria counts: < 0.1 CFU/100ml

Typical water purification stages:











HPR QA

- Online monitoring of TOC, resistivity and particulate counts
- Collection of water from rinsed cavity for particulate analysis













HPR Systems



HPR stand inside the clean room at JLab











HPR Systems





HPR stand inside the clean room at DESY









HPR spray heads optimization



Very effective on irises

Equator fill with water → too high flow rate

- For a given pump displacement the nozzle opening diameter and number of nozzles sets the system pressure and flow rate
- HPR spray heads needs to be optimized for a particular cavity geometry!









HPR Jet Characterization





Use a load cell to measure the force vs. distance of the water jet

$$F = \rho \cdot Q \cdot u \qquad u = \sqrt{\frac{2 \cdot p}{\rho}}$$

u = velocity

Q = flow

p = pressure

 ρ = density

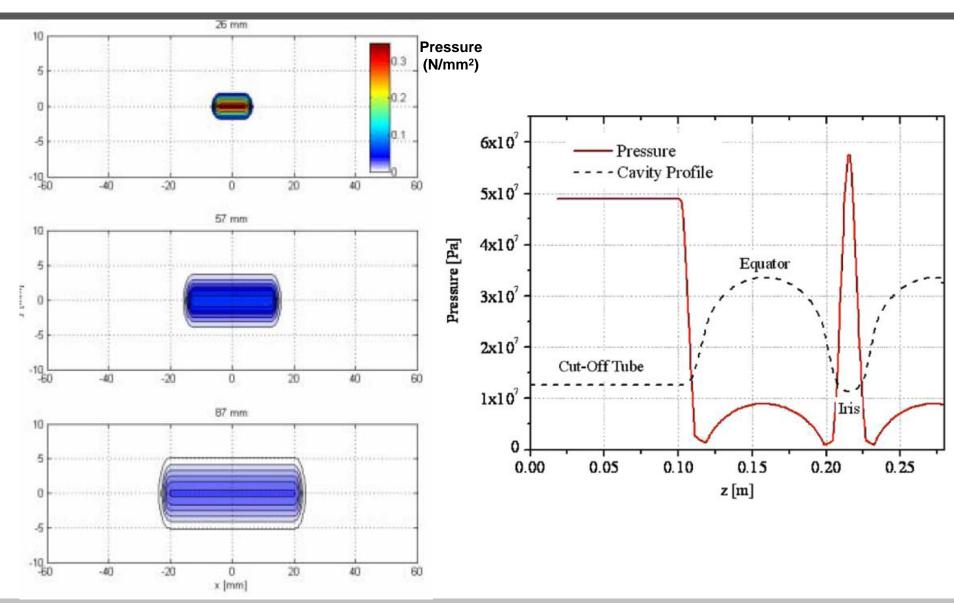








Water Pressure vs. Distance









Different HPR Configurations

Lab.	# nozzles	Tested nozzles	Flow [l/min] (1 nozzle)	Pump Press [bar]
JLAB Prod	2	SSC-FAN: 1502 4002 40015	5@85 bar	85
JLAB R&D	2	SSC-FAN 1502	5@85 bar	0.5
	9	Φ=0.4 mm Sapphire		85
KEK Tsukuba	8	Ф=0.6 mm SS	1.5@70 bar	70-50
KEK Nomura	8	Φ=0.6 mm SS Φ=0.6 mm SS	1.1@50 bar 0.9@40 bar	50-40
DESY	8	Φ=0.6 mm Sapphire	1.6@100 bar	90-110

• "Fan" jet allows greater surface coverage compared to a standard round jet

• HPR Duration: 3 - 12 h on 9-cell cavity

• Cavity rotation: 2 – 20 rpm

• Wand movement: 8 - 50 mm/min









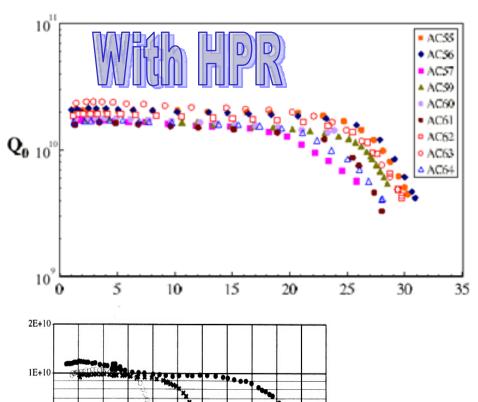
Performance Improvement After HPR

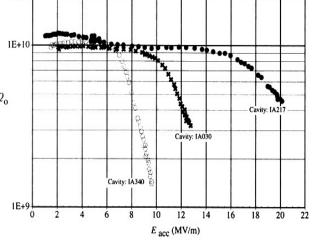


TESLA Cavities



CEBAF Cavities















HPR Issues



ISSUES:

- HPR systems are still not optimized for the best surface cleaning performance
- Surface left in a vulnerable state, wet





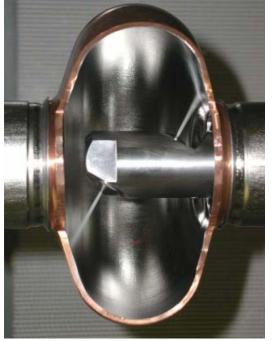


Dry Ice Cleaning

- Complementary method to HPR, developed at DESY
- Liquid CO₂ jet flowing through a nozzle and resulting in a snow/gas mixture at a temperature of 194 K

 Removal of hydrocarbons and sub-micron particles while keeping the surface dry by

- Thermal
- Mechanical
- Chemical
- Could be applied to a fully assembled cavity mounted horizontally as a part of a "cavity-string"











Required Procedures for Qualifying SRF Cavities

- Degreasing surfaces to remove contaminates
- Chemical removal of exterior films incurred from welding
- Removal of damage layer of niobium from fabrication (~150 μm)
- Removal of hydrogen from bulk Nb
- Mechanical tuning
- Chemical removal of internal surface for clean assembly (10-20 μm)
 - Additional "cleaning" steps if Electropolishing (EP) is used
- High Pressure Rinsing (HPR) to remove particulates from interior surfaces (incurred during chemistry and handling)
- Drying of cavity for assembly in cleanroom (reduce risk of particulate adhesion and reduce wear on vacuum systems)
- Clean assembly
- Clean evacuation
- Low-temperature baking



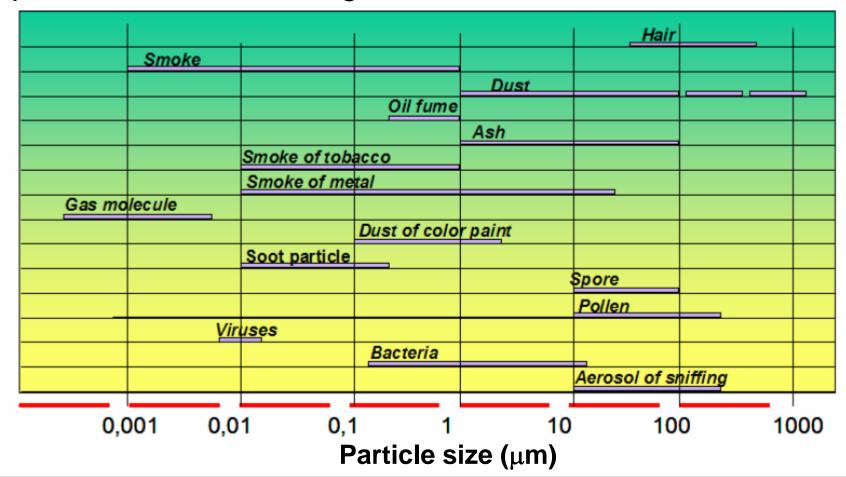






Particulates in Air

 Cleanroom technology is required to prevent airborne particulates from settling on the surface of SRF cavities



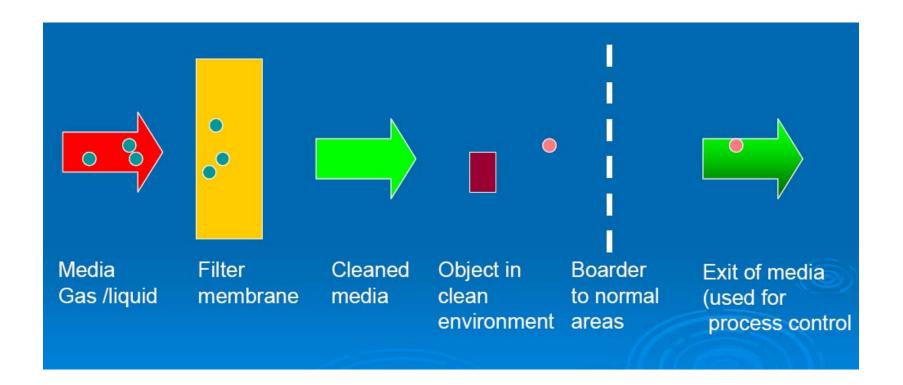






Cleanroom Technology

Cleanroom: a controlled environment in which all incoming air, water and chemicals are filtered to meet high standards of purity. Temperature, humidity and pressure are controlled, but the key element is air filtrations.



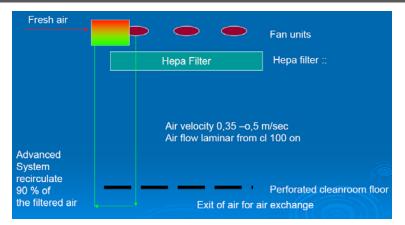


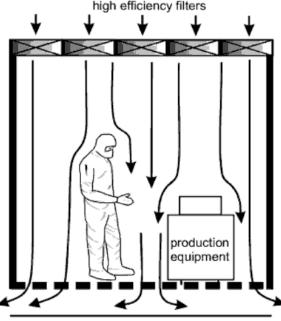




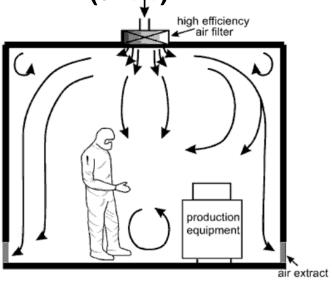


Type of Cleanrooms





Non-Unidirectional airflow type (JLab)



Unidirectional airflow type (DESY)









Cleanroom Classification

ISO Classification number	Maximum concentration limits (particles/m³ of air) for particles equal to and larger than the considered sizes shown below										
	>=0.1µn	≻=0.1μm>=0.2μm		>=0.3µm		>=0.5μm		>=1μm		>=5.0µm	
ISO Class 1	10	2									
ISO Class 2	100	24	10		4						
ISO Class 3	1 000	237	102	102		35		8			
ISO Class 4	10 000	2 370	1 020	1 020		352		83			
ISO Class 5	100 000	23 700	10 20	0	3 520		832		29		
ISO Class 6	1 000 000	237 000	102 000		35 200		8 320		293		
ISO Class 7					352 00	00	83 20	00	2 930		
ISO Class 8					3 520 000		832 000		29 300		
ISO Class 9					35 200 000		8 320 000		293 000		
ISO 14644-1 Classes	Class 3	Class 4		Class 5		Class 6		Class 7		Class 8	
FS 209 Classes	Class1	Class 10)	Class 10	00	0 Class 100		00 Class 10		Class 100, 000	
	Cavity (assembly				leanroom for SRF						

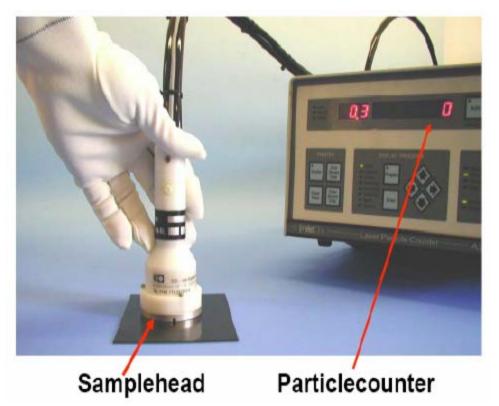








Particle Counters











People in Cleanrooms

- People are a major source of particulate contamination inside a clean room through:
 - Body Regenerative Processes Skin flakes, oils, perspiration and hair.
 - Behavior Rate of movement, sneezing and coughing.
 - Attitude Work habits and communication between workers.











Assembly: Vacuum Hardware

 The cavity strings have to be vacuum tight to a leak rate of < 1 x10⁻¹⁰ torr l/sec

 The sealing gaskets and hardware have to be reliable and particulate-free

 The clamping hardware should minimize the space needed for connecting the beamlines





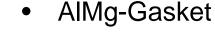


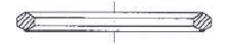
Assembly: Vacuum Hardware

Present choice for ILC cavities:

diamond-shaped AIMg₃ –gaskets + NbTi flanges + bolts

Also used for SNS cavities







Alternative:

radial wedge clamp, successfully used for CEBAF upgrade cavities

Radial Wedge Clamp











Cavity Assembly













Required Procedures for Qualifying SRF Cavities

- Degreasing surfaces to remove contaminates
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- Clean assembly
- Clean evacuation
- Low-temperature baking

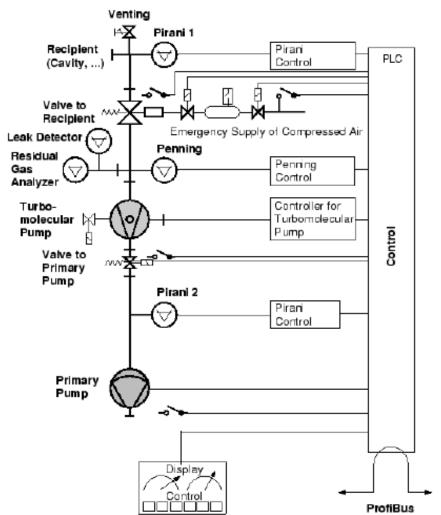




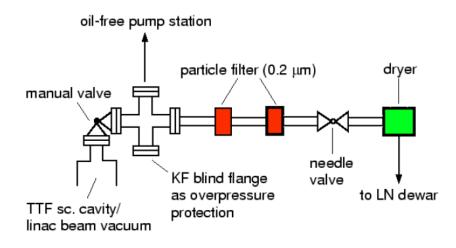




Clean Evacuation



- Oil-free pump stations with leak check and residual gas analyzer
- Laminar venting with pure, particle filtered N₂ or Ar







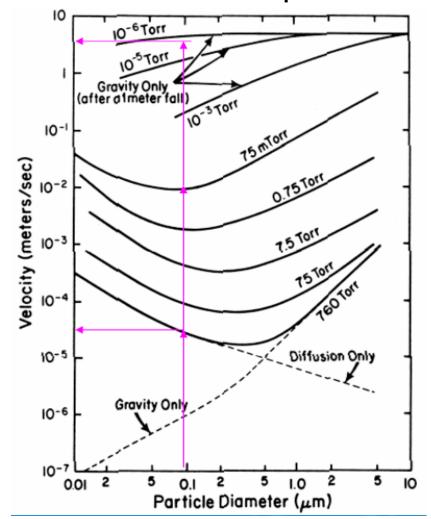




Clean Vacuum Systems

"Dirty" or "contaminated"
 (hydrocarbons, air leaks)
 vacuum system can recontaminate the surface of a clean cavity!

Settling velocity for particles in air at room temperature











Required Procedures for Qualifying SRF Cavities

- Degreasing surfaces to remove contaminates
- Chemical removal of exterior films incurred from welding
- Removal of damage layer of niobium from fabrication (\sim 150 μ m)
- Removal of hydrogen from bulk Nb
- Mechanical tuning
- Chemical removal of internal surface for clean assembly (10-20 μm)
 - Additional "cleaning" steps if Electropolishing (EP) is used
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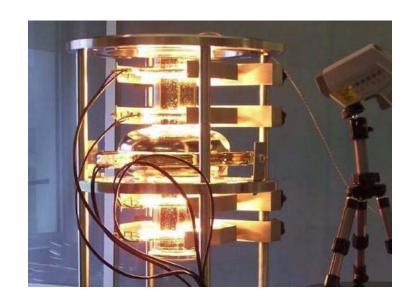


Low-Temperature Baking



Hot N₂ gas uniformly heats up the cavity (JLab)

Infrared heaters heating the open cavity inside the cleanroom (Saclay)



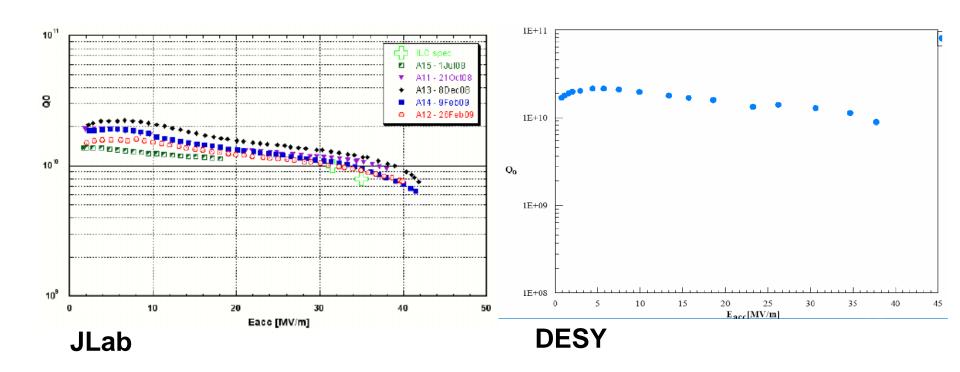








If Everything Works Well...



 $E_p \cong 80$ MV/m, $B_p \cong 170$ mT can be achieved in the vertical test of 9-cell ILC cavities (~ 1 m² of Nb surface)









Additional Steps for Cavity String

- Final mechanical tuning
- He-vessel welding
- Degreasing
- Final material removal (10-20 μm)
- Final HPR
- Horizontal assembly into cavity-string
- Evacuation of cavity string









Helium Vessel Welding













String Assembly

- A cavity string is assembled in a class 10 or class 100 clean room on an assembly bench over a period of several days after they have been qualified in a vertical or horizontal test.
- Prior to assembly, the cavities are high pressure rinsed for several hours, dried in a class 10 clean room, mounted onto the assembly bench and auxiliary parts are attached.
- The most critical part of the assembly is the interconnection between two cavities, monitored by particle counting

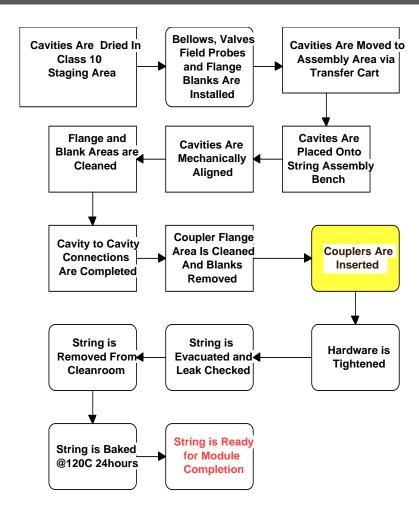








Example of Cavity Assembly Sequence

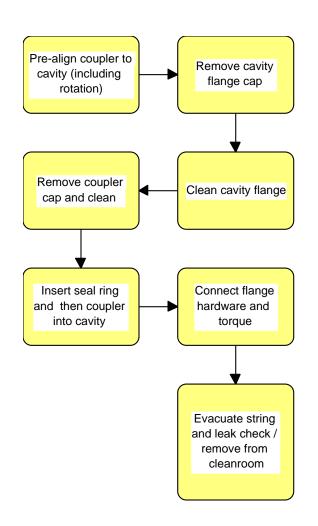


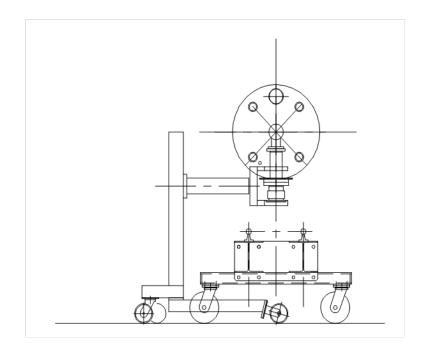






Coupler Insertion Procedure













String Assembly





SNS β_g =0.61 string at JLab: 3 cavities per string

XFEL at DESY: 8 cavities per string



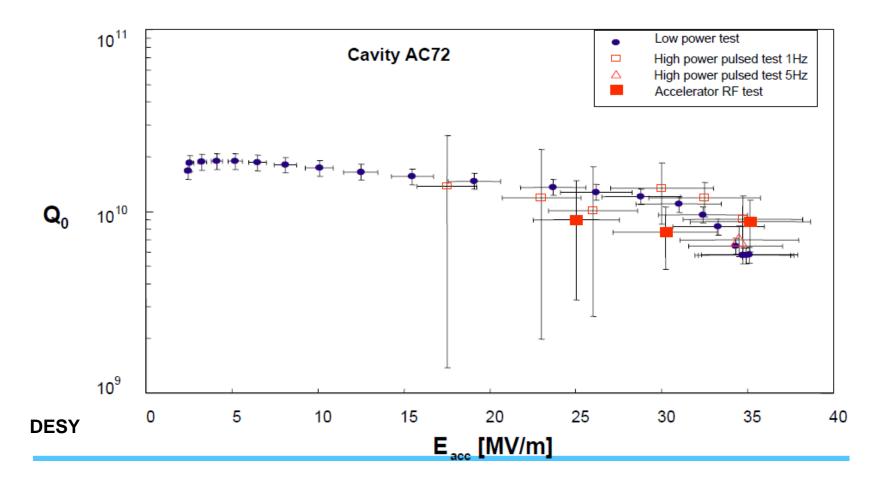






If Everything Works Well...

35 MV/m without field emission in operation with electron beam is possible!











Comments on Facilities and Process Steps

RF Cavities

 RF structures have excellent quality in materials and fabrication but flange designs require significant hardware for assembly and extensive manual labor → lots of room for errors

Facilities

- Cleanroom environments are typically excellent, easy to monitor
- DI water quality excellent in most cases, easy to monitor
- Sub-component cleaning not at same level with cleaning quality for cavities
- Many system failures reported, leading to large recovery times
- No two process system designs the same

Process Steps

- Assembly steps present the most interaction and largest source of particulate contamination, very difficult to monitor
- Subcomponent cleaning insufficient but easy to monitor
- BCP Chemistry in good control easy to monitor
- EP currently has less process control and more process variables









History Plot of High Gradient

